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# Broadband Supercontinuum Generation in Mid-Infrared Range ( $0.8 \mu\text{m} - 4.5 \mu\text{m}$ ) Using Low Power Dispersion-Engineered CMOS Compatible Silicon-Rich Nitride (SRN) Waveguide

**Abstract**—We numerically modeled a complementary metal-oxide-semiconductor (CMOS) compatible 5-mm-long rectangular waveguide for broadband mid-infrared (MIR) supercontinuum (SCG) generation. The waveguide is constituted using Si-Rich Nitride (SRN) as a core and  $\text{LiNbO}_3$  glass for its top and bottom claddings. The proposed waveguide structure is optimized for pumping only in the anomalous dispersion regime. Numerical analysis reveals that a wideband SCG into the MIR spanning the wavelength  $0.8 \mu\text{m}$  to  $4.5 \mu\text{m}$  could be generated by the proposed geometry using a very low pulse peak power of 40 W having width of 50-fs employing pump at  $1.55 \mu\text{m}$  wavelength.

**Index Terms**—Silicon-rich Silicon nitride, Planar waveguide, Dispersion, Supercontinuum generation,

## I. INTRODUCTION

Generation of supercontinuum (SCG) has drawn a significant attraction because of having capability of creating a very broad continuous spectrum and having important applications in spectroscopy, optical coherence tomography (OCT) and biomedical applications [1]. Developed technology in microstructured fiber design and fabrication ensures the improvement of SCG source which can operate in the extended region from deep ultraviolet (UV) to mid-infrared (MIR) region [2]. Recently Silicon-On-Insulator (SOI) technology facilitates the use of Complementary Metal Oxide Semiconductor (CMOS) fabrication effectively to build low cost and scalable integrated optical components similar to silicon photonics which is a promising candidate for broadband supercontinuum (SC) generation in the MIR [3].

Silicon rich nitride (SRN) consist of 65% Silicon (Si) and 35% Nitrogen (N) contains a huge bandgap of 2.05 eV which eliminates the Two-Photon Absorption (TPA) at  $1.55 \mu\text{m}$  [4]. The Kerr nonlinearity of  $2.8 \times 10^{13} \text{ cm}^2/\text{W}$  (4 times larger than that of silicon) and refractive index of about 3.1 to tailor dispersion [5]. The loss is taken for merely material by ignoring substrate linkage is 6 dB/cm since of Si-H bonds formation for chemical vapor deposition [6].

Recently a few research groups have demonstrated SCG generation using SRN waveguides [5], [7]. Ting *et al* [5] demonstrated  $1.13 \mu\text{m}$  to  $1.75 \mu\text{m}$  spectrum broadening in  $\text{SiO}_2$  overlaid SRN waveguide  $\text{SiO}_2$  is used as cladding by pumping at  $1.55 \mu\text{m}$  with 500 fs duration at peak power 140 W. Liu *et al* [7] demonstrated spectrum spanning  $0.82 \mu\text{m}$  to  $2.25 \mu\text{m}$  through 10 mm long SRN waveguide using

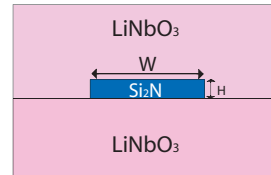


Fig. 1: The schematic diagram of proposed SRN waveguide structure with  $H = 0.5 \mu\text{m}$  and  $W = 3 \mu\text{m}$ .

Er-Fiber laser pumped at  $1.55 \mu\text{m}$  as the center frequency with 105 fs duration at peak power 1330 W theoretically and experimentally.

In our proposed work, a 5 mm-long dispersion-engineered CMOS compatible SRN waveguide for broadband SCG generation in anomalous dispersion region is numerically investigated. A spectrum broadening from  $0.8 \mu\text{m}$  to  $4.5 \mu\text{m}$  is observed by pumping at the wavelength of  $1.55 \mu\text{m}$  with a TE polarized 50 fs duration full-width half maximum sech pulse at a peak power of 40 W. It is worth to mention that most of the aforementioned work described earlier, researchers used  $\text{SiO}_2$  as cladding for the modeling of SRN waveguides. Since  $\text{SiO}_2$  affects by high material absorption loss in the MIR region more than  $2.3 \mu\text{m}$  and  $\text{LiNbO}_3$  glass as cladding has transparency beyond  $4 \mu\text{m}$ , thus we considered  $\text{LiNbO}_3$  as cladding in proposed CMOS compatible waveguide design. To the best of our knowledge, it is the first time proposed  $\text{LiNbO}_3$  claded SRN waveguide for SC generation.

## II. MODELING AND METHOD

The geometric structure of the proposed rectangular waveguide made of SRN as a core and  $\text{LiNbO}_3$  glass as a cladding is shown in Fig. 1. In the simulation, the necessary linear refractive indices of  $\text{Si}_2\text{N}$  and  $\text{LiNbO}_3$  glasses are calculated using the Sellmeier Eqs. 1 and 2 that are taken from [4] and [8], respectively.

$$n(\lambda) = 1 + \sqrt{1 + \sum_{k=1}^N \frac{\alpha_k \lambda^2}{\lambda^2 - \beta_k^2}} \quad (1)$$

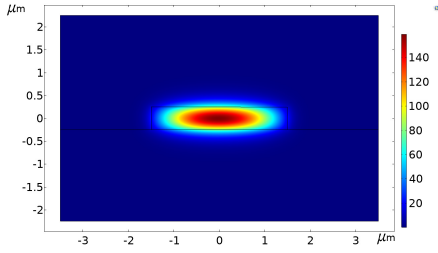


Fig. 2: Field profile at 1.55  $\mu\text{m}$  of proposed waveguide for fundamental quasi-TE mode.

$$n(\lambda) = \sqrt{1 + \sum_{k=1}^N \frac{\alpha_k \lambda^2}{\lambda^2 - \beta_k^2}} \quad (2)$$

The respective value for described coefficients  $\alpha$ ,  $\beta$  in Equation 1 and Equation 2 are given in table I.

TABLE I: Sellmeier Coefficients

Materials	SRN ( $Si_2N$ )		$LiNbO_3$	
	N	$\alpha_k$	$\beta_k$	$\beta_k$
k=1	2.21715	0.0632602	2.67334	0.01764
k=2	1.12108	0.249134	1.2290	0.054914
k=3	24.8224	250.091	12.614	474.600
k=4	17.6617	251.079	-	-

The numerical analysis is performed by using the finite element analysis (FEA) based simulation software COMSOL Multiphysics. Initially all the mode propagation constant  $\beta(\omega)$ , have to be calculated for fundamental quasi-TE mode using COMSOL, then using these values to calculate any refractive index distribution for a certain range of the desired wavelength. The field pattern for fundamental quasi-TE mode is shown in Figure 2 for the proposed waveguide geometry of thickness,  $H = 0.5 \mu\text{m}$  and width,  $W = 3 \mu\text{m}$  at 1.55  $\mu\text{m}$  pump wavelength. The group velocity of dispersion (GVD) which is a very important parameter is calculated by using the following Eq. 3 [9]

$$D(\lambda) = -\frac{\lambda}{c} \frac{d^2 \text{Re}(n_{\text{eff}})}{d\lambda^2} \quad (3)$$

Broadband MIR SC generation for the proposed waveguide have been studied by using the Generalized Nonlinear Schrödinger Equation (GNLSE) for anomalous dispersion of single-polarization propagation [10]. Raman effect of SRN is very low so that it can be neglected in SRN waveguide simulation [11].

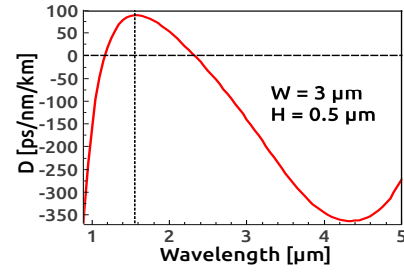


Fig. 3: The tailored GVD curve for the proposed SRN waveguide structure. Vertical dotted line represents the pump wavelength of 1.55  $\mu\text{m}$ .

$$\frac{\partial A}{\partial z} = -\frac{\alpha}{2} A + \sum_{k \geq 2} \frac{i^{k+1}}{k!} \beta_k \frac{\partial A^k}{\partial T^k} + i\gamma(|A|^2 A + \frac{i}{\omega_0} \frac{\partial}{\partial z} |A|^2 A) \quad (4)$$

In GNLSE Equation,  $A(z,T)$  is denoted the pulse envelopes which evolves throughout wavelength of waveguide in a retarded time frame with reference  $T = t - \beta_1 Z$  moving at the group velocity  $v_g = \frac{1}{\beta_1}$ .  $\beta_k$  ( $k \geq 2$ ) is the higher order Taylor series expanded dispersion coefficients around the center angular frequency  $\omega_0$  and associated attenuation of SRN waveguide is  $\alpha$ . The nonlinear parameter is described as  $\gamma = \frac{n_2 \omega_0}{c A_{\text{eff}}}$  where  $n_2$  is Kerr-nonlinearity at pump wavelength and  $A_{\text{eff}} = \frac{(\int \int |E|^2 dx dy)^2}{(\int \int |E|^4 dx dy)}$  is mode effective area for fundamental mode [12].

### III. NUMRICAL RESULTS

To get a compact and efficient SCG spectrum at the waveguide's output, the GVD is the most important key parameter. For the expansion of SCG spectra UV to the MIR region, a planar waveguide made of SRN can be modeled for pumping in either normal or anomalous dispersion region. Initially, the detail numerical analysis is carried out for several geometries by changing the waveguide transverse dimensions such as width ( $W$ ) and height ( $H$ ) for employing pump at 1.55  $\mu\text{m}$  to obtain expanded SCG beyond the MIR region. Since the

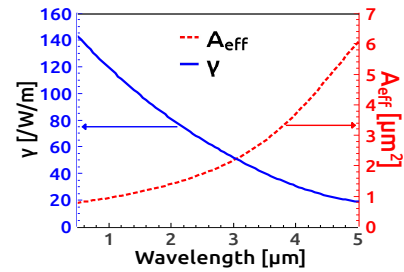


Fig. 4: Mode effective area and nonlinearity curves of proposed SRN waveguide structure with  $H = 0.5 \mu\text{m}$  and  $W = 3 \mu\text{m}$ .

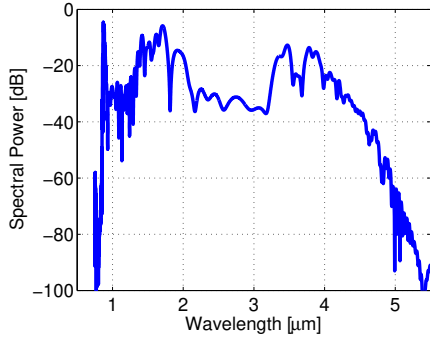


Fig. 5: SC spectrum at the waveguide output is shown by pumping at  $1.55 \mu\text{m}$  in anomalous dispersion region with a low input peak power of 40 W.

zero-dispersion wavelength (ZDW) is playing an vital role in the SC generation, the waveguide is engineered in such a way that the pump source can be employed close to ZDW at the anomalous region for extending the SCG beyond SRN material transparency limit  $> 5 \mu\text{m}$ . The transverse electric field (TE) for fundamental quasi mode was used for designing the model. The electric field plot for fundamental quasi-TE mode is described in Fig. 2 obtained from COMSOL. The maximum electric field value is obtained 157 V/m in core confinement of fundamental mode and decreased it to a minimum of 20 V/m in the cladding region. The GVD was calculated by using the Eq. 3 of an effective refractive index for wavelength region  $0.5 \mu\text{m}$  to  $5 \mu\text{m}$  through COMSOL. To obtain  $n_{\text{eff}}$  value, the Sellmeier Equations for SRN and  $\text{LiNbO}_3$  depicted in Eqs. 1 and 2 were used. The GVD curve in Fig. 3 is obtained for waveguide structure of  $H = 0.5 \mu\text{m}$ ,  $W = 3 \mu\text{m}$  and the calculated dispersion is  $89.4 \text{ ps/nm/km}$  at the pump wavelength of  $1.55 \mu\text{m}$ . From the figure, it is noted that two ZDW at  $1.2 \mu\text{m}$  and  $2.5 \mu\text{m}$  are obtained which play a significant role for the expansion of SCG in the longer wavelength region.

The GNLS equation is solved by using a symmetrized split-step Fourier method [9]. For simulation,  $2^{13}$  grid points are taken. The time step is chosen 2.76 fs for eliminating negative frequency generation in the frequency grid. In the direction of propagation, the axial number of steps is considered as 100 000 with a step size of  $0.1 \mu\text{m}$ . The waveguide is modeled for pumping at  $1.55 \mu\text{m}$  wavelength with a TE polarized 50 fs duration sech pulse at a pulse peak power of 40 W. The spurious-free spectral broadening is ensured by calculating the higher-order  $\beta(\omega)$  up to 12th order. Mode effective area ( $A_{\text{eff}}$ ) and nonlinear coefficient ( $\gamma$ ) for the proposed structure for the wavelength range of interests are calculated by using FEM mode solver which is depicted in Figure 4. The estimated  $A_{\text{eff}}$  and  $\gamma$  at  $1.55 \mu\text{m}$  are calculated as  $1.17 \mu\text{m}^2$  and  $96.81 \text{ /W/m}$  where the nonlinear parameter  $n_2 = 2.8 \times 10^{-13} \text{ cm}^2/\text{W}$  and propagation loss  $\alpha = 6 \text{ dB/cm}$  are taken from [4].

Figure 5 depicts the SCG spectrum spanning from near-IR to MIR for the proposed geometry where it can be observed

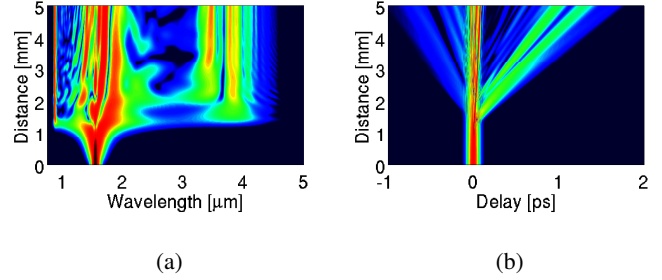


Fig. 6: (a) Spectral and (b) Temporal density evolutions are plotted in  $1.55 \mu\text{m}$  pump wavelength.

that spectral broadening occurs from  $0.8$  to  $4.5 \mu\text{m}$  ( $-40 \text{ dB}$  equivalent level from peak). The corresponding spectral and temporal evolutions are depicted in Figs. 6a and 6b from which it can be seen that the soliton fission occurs at a length of  $1.2 \text{ mm}$  along the waveguide and the number of solitons induced is 5. Since there is no Raman scattering, no Raman induced self-frequency shift is evolved. The self phase modulation is observed in the broadening near the pump wavelength due to applied self-compression of given pulses. Two dispersive waves (DWs) have appeared in short and long-wavelength side of the spectrum due to the existence of two ZDWs in the respective GVD curve described in Figure 3. The first DW is located at around  $900 \text{ nm}$  and the center of long wavelength DW is located approximately at around  $4 \mu\text{m}$ .

#### IV. CONCLUSION

In this work, a CMOS-compatible novel planar structure using SRN material is proposed for broadband SCG in the MIR. A 5-mm-long on-chip compatible geometry, which is modeled using  $\text{Si}_2\text{N}$  as a core and  $\text{LiNbO}_3$  glass for its upper and lower claddings, generates an SC spanning up to  $4.5 \mu\text{m}$  into the MIR with a very low pulse peak power of 40 W employing pump at  $1.55 \mu\text{m}$  wavelength. This is the widest SCG spanning, to the best of our knowledge, in the MIR using planar SRN waveguide which can be used for several MIR region applications.

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